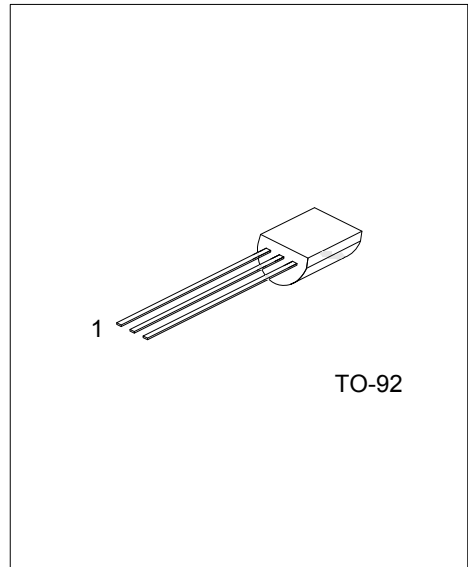


**S8050****NPN SILICON TRANSISTOR****LOW VOLTAGE HIGH
CURRENT SMALL SIGNAL
NPN TRANSISTOR****DESCRIPTION**

The UTC **S8050** is a low voltage high current small signal NPN transistor, designed for Class B push-pull audio amplifier and general purpose applications.

FEATURES

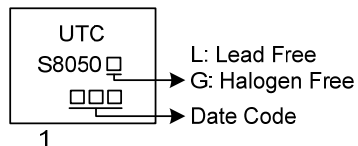
- * Collector current up to 700mA
- * Collector-Emitter voltage up to 20 V
- * Complementary to S8550

**ORDERING INFORMATION**

Order Number		Package	Pin Assignment			Packing
Lead Free Plating	Halogen Free		1	2	3	
S8050L-x-T92-B	S8050G-x-T92-B	TO-92	E	B	C	Tape Box
S8050L-x-T92-K	S8050G-x-T92-K	TO-92	E	B	C	Bulk

Note: Pin Assignment: E: Emitter B: Base C: Collector

S8050G-x-T92-B (1)Packing Type (2)Package Type (3)Rank (4)Green Package	(1) B: Tape Box, K: Bulk (2) T92: TO-92 (3) x: refer to Classification of h_{FE2} (4) G: Halogen Free and Lead Free, L: Lead Free
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MARKING

■ **ABSOLUTE MAXIMUM RATING** ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	700	mA
Collector Dissipation ($T_A=25^\circ\text{C}$)	P_C	1	W
Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

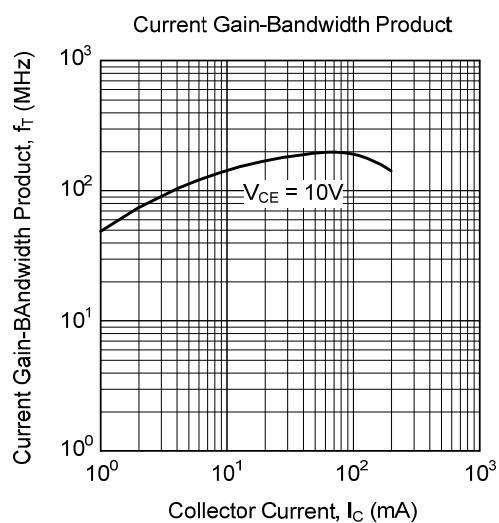
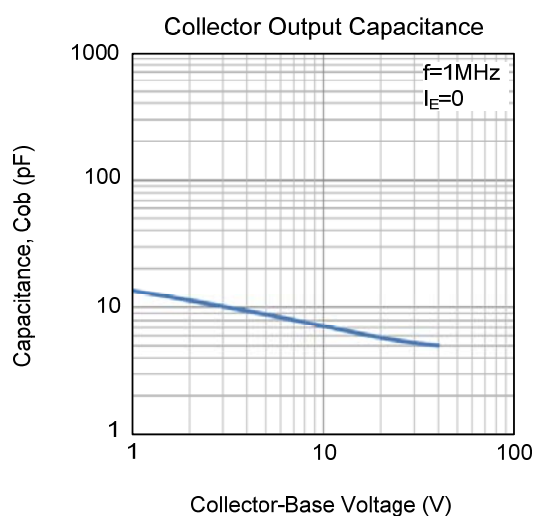
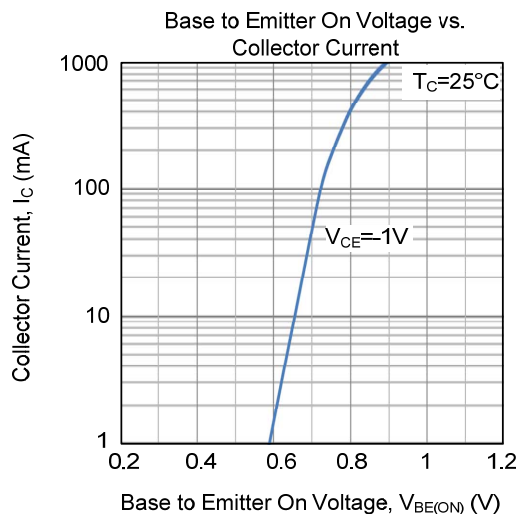
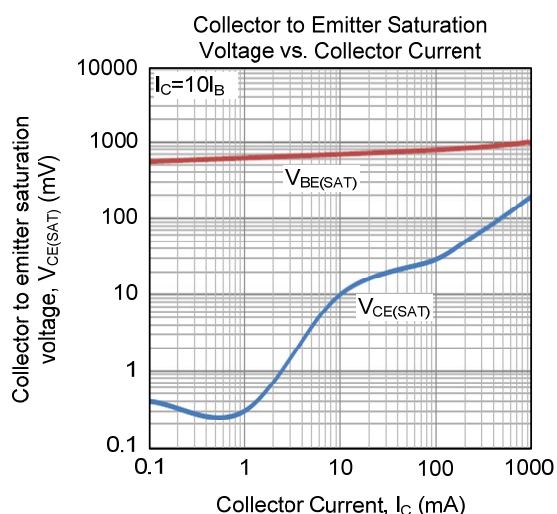
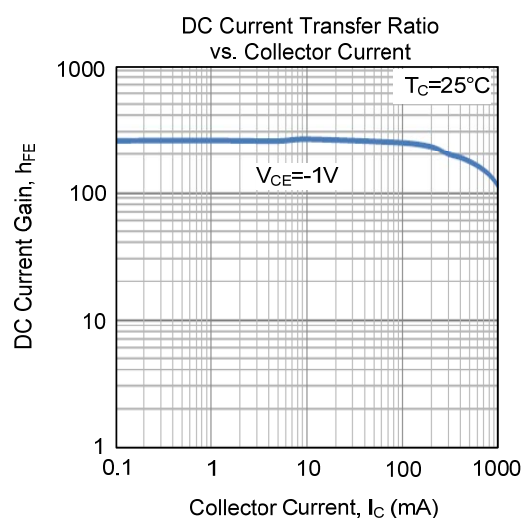
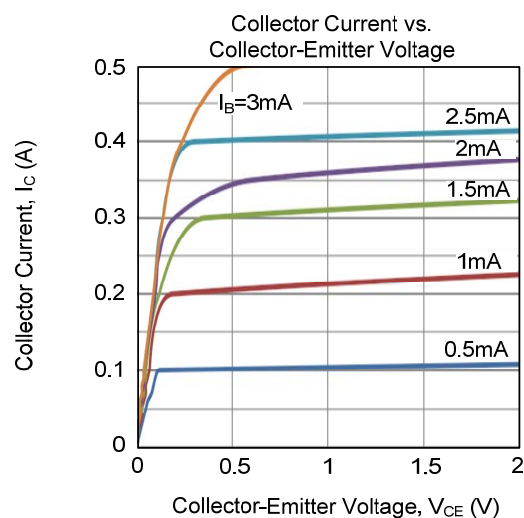
■ **ELECTRICAL CHARACTERISTICS** ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=100\mu\text{A}$, $I_E=0$	30			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=1\text{mA}$, $I_B=0$	20			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=100\mu\text{A}$, $I_C=0$	5			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=30\text{V}$, $I_E=0$			1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5\text{V}$, $I_C=0$			100	nA
DC Current Gain	h_{FE1}	$V_{CE}=1\text{V}$, $I_C=1\text{mA}$	100			
	h_{FE2}	$V_{CE}=1\text{V}$, $I_C=150\text{mA}$	120		400	
	h_{FE3}	$V_{CE}=1\text{V}$, $I_C=500\text{mA}$	40			
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$			0.5	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$			1.2	V
Base-Emitter Saturation Voltage	V_{BE}	$V_{CE}=1\text{V}$, $I_C=10\text{mA}$			1.0	V
Current Gain Bandwidth Product	f_T	$V_{CE}=10\text{V}$, $I_C=50\text{mA}$	100			MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$		9.0		pF

■ **CLASSIFICATION OF h_{FE2}**

RANK	C	D	E
RANGE	120-200	160-300	280-400

■ TYPICAL CHARACTERISTICS



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